



Small IPM (Intelligent Power Module) P633C Series 6MBP\*\*XS\*065-50

# **Application Manual**





This Instruction contains the product specifications, characteristics, data, materials, and structures as of August 2023. The contents are subject to change without notice for specification changes or other reason. When using a product listed in this Instruction be sure to obtain the latest specifications.

The application examples in this note show the typical examples of using Fuji products and this note shall neither assure to enforce the industrial property including some other rights nor grant the license.

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The products described in this application manual are manufactured with the intention of being used in the following industrial electronic and electrical devices that require normal reliability.

- Compressor motor inverter
- Fan motor inverter for room air conditioner
- Compressor motor inverter for heat pump applications, etc.

If you need to use a semiconductor product in this application note for equipment requiring higher reliability than normal, such as listed below, be sure to contact Fuji Electric Co., Ltd. to obtain prior approval. When using these products, take adequate safety measures such as a backup system to prevent the equipment from malfunctioning when a Fuji Electric's product incorporated in the equipment becomes faulty.

- •Transportation equipment (mounted on vehicles and ships)
- Trunk communications equipment
- Traffic-signal control equipment
- Gas leakage detectors with an auto-shutoff function
- Disaster prevention / security equipment
- ·Safety devices, etc.

Do not use a product in this application note for equipment requiring extremely high reliability such as:

- Space equipment
   Airborne equipment
   Atomic control equipment
- Submarine repeater equipment
   Medical equipment

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# Chapter 4 Power Terminals

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In this chapter, the guideline and precautions in circuit design on the power terminals, such as how to determine the resistance of shunt resistor are explained.

### 1. Connection of Bus Input terminal and low-side Emitters

#### <Description of the power terminals>

Table 4-1 shows the details about the power terminals.

Table 4-1 Detailed description of power terminals

Terminal	Name	Description
Р		Positive bus voltage input terminal It is internally connected to the collector of the high side IGBTs. In order to suppress the surge voltage caused by the wiring or PCB pattern inductance of the bus voltage, connect a snubber capacitor close to this terminal. (Typically metal film capacitors are used)
U, V,	W	Inverter output terminals for connecting to motor load.
N(U), N(V)	), N(W)	Negative bus voltage input terminals These terminals are connected to the low side IGBT emitter of each phase. In order to monitor the current on each phase, shunt resistors are connected between these terminals and the negative bus voltage input (power ground).

#### <Recommended wiring of shunt resistor and snubber capacitor>

- Connect external shunt resistors to detect over current (OC) condition and phase currents.
- Long wiring patterns between the shunt resistor and the product will cause excessive surge voltage
  that might damage the internal control IC and current detection components. To reduce the pattern
  inductance, the wiring between the shunt resistors and the product should be as short as possible.
- As shown in the Fig.4-1, snubber capacitors should be connected at the right location to suppress surge voltage effectively.
- Connecting the snubber capacitor at location "C" is recommended. If the snubber capacitor is connected at location "A" as shown in the Fig.4-1, the snubber capacitor cannot suppress the surge voltage effectively because the wiring inductance is not negligible. If the capacitor is connected at the location "B", the charging and discharging current of snubber capacitor will flow through the shunt resistor. This will impact the current detection signal and the OC protection level will be lower than the design value. Although the surge voltage suppression effect when the snubber capacitor is connected at location "B" is greater than that at location "A" or "C", location "C" is recommended considering the impact to the current detection accuracy.
- Snubber capacity of 0.1 ~ 0.22 μF is recommended.



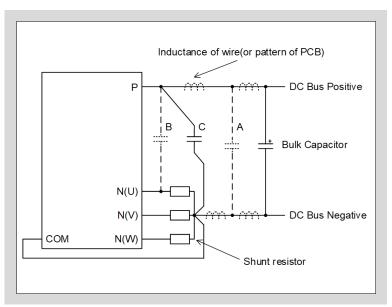


Fig.4-1 Recommended wiring of shunt resistor and snubber capacitor

## 2. Setting of Shunt Resistor for Over Current Protection

#### <Selecting current sensing shunt resistor>

The value of current sensing resistor is calculated by the following equation:

$$R_{\rm Sh} = \frac{V_{\rm IS(ref)}}{I_{\rm OC}} \tag{4.1}$$

- Where V<sub>IS(ref)</sub> is the over current (OC) protection reference voltage level of the product and I<sub>OC</sub> is the current of OC detection level. V<sub>IS(ref)</sub> is 0.455V(min.), 0.48V(typ.) and 0.505V(max.). And R<sub>Sh</sub> is the Resistance of the shunt resistor.
- The maximum value of OC level should be set lower than the repetitive peak collector current in the specification datasheet of this product, taking into consideration the variation in shunt resistance.
- For example, if OC level is set at 45A, the recommended value of the shunt resistor is calculated as:

$$R_{\rm Sh(min)} = \frac{V_{\rm IS(ref)(max)}}{I_{\rm OC}} = \frac{0.505}{45} = 11.2[m\Omega]$$
 (4.2)

•  $R_{Sh(min)}$  is the minimum resistance of the shunt resistor. It should be noted that a proper resistance should be chosen considering OC level required in practical application.

#### <Filter delay time setting of over current protection>

- An external RC filter is necessary in the over current sensing circuit to prevent unnecessary over current protection caused by noise. The RC time constant is determined by the noise application time noise and the short circuit withstand capability of IGBTs. It is recommended to be set approximately 0.7µs.
- When the voltage across the shunt resistor exceeds the OC level, the filter delay time  $t_{\rm delay}$  that delays the rises of input voltage of IS terminal to the OC level is determined by the RC filter time constant and is given by the following equation:



$$t_{\rm delay} = -\tau \cdot \ln \left( 1 - \frac{V_{\rm IS(ref)(max)}}{R_{\rm Sh} \cdot I_{\rm p}} \right) \tag{4.3}$$

- $\tau$  is the RC time constant,  $I_P$  is the peak current flowing through the shunt resistor. In addition, there is a shut down propagation delay  $t_{d(IS)}$  of OC.
- Therefore, the total time  $t_{total}$  from OC triggered to shut down of the IGBT is given by:

$$t_{\text{total}} = t_{\text{delay}} + t_{\text{d(IS)}} \tag{4.4}$$

• The total delay time  $t_{\text{total}}$  should be shorter than the short circuit withstands capability of IGBT. Please confirm the proper delay time in actual equipment.